Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	3333	anode with (hole near2 injection)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/22 09:00
S2	2774	cathode with (electron adj injection)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 13:16
S3	69851	(organic adj ((light adj emiting) electroluminescen\$2)) electroluminescen\$2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/22 10:07
S4	1559	S1 and S2 and S3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 13:17
S5	36405	charge adj2 ((generation adj layer) layer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 13:17
S6	99736	(organic (light adj emission)) adj layer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 13:18
S7	213	S4 and S5 and S6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 13:18
S8	20789	work adj function	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 15:34

S9	5410	ionization adj potential	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 13:18
S10	488	S8 same S9	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 13:19
S11	22	S7 and S10	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 13:33
S12	4898	electron near2 affinity	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 13:33
S13	46	S7 and S12	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 14:41
S14	8	("6472817" "20030030717" "2003168553" "20050151824").pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 14:42
S15	4	("5546413"   "5703436"   "5994835"   "6160828").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/04/21 15:10
S16	3	("5151628"   "5200668"   "5487953").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/04/21 15:10
S17	8	("5994835").URPN.	USPAT	OR	ON	2006/04/21 15:12
S18	8665	((organic adj ((light adj emiting) electroluminescen\$2)) electroluminescen\$2) near2 layer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 15:17

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S19	240	S18 near3 plural\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 15:19
S20	7	S19 and waveguide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 15:20
S21	0	S19 and print\$head	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 15:21
S22	17	S19 and printer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 15:23
S23	1475	S18 same anode same cathode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 15:23
S24	339	S23 and (plural\$3 near2 layer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 15:32
S25	134	S23 and (print\$head printer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 15:25
S26		S24 and (print\$head printer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 15:25

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S27	0	S14 and (plural\$3 near2 layer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 15:32
S28	1	(work adj function) and S14	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 15:45
S29	2	"09/740858"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 15:52
S30	0	"20030189401".pn. and (hole adj2 electrode)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 15:52
S31	2	"20030189401".pn. and (anode cathode)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 16:11
532	1	"10/665011"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 16:17
S33	1	"20040027059".pn. and substrate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 16:18
S34	1	"20040027059".pn. and (anode substrate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 16:37

S35	1	"20040027059".pn. and (electron affinity)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 18:04
S36	1	"20040027059".pn. and (potential difference ev)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/22 09:56
S37	1	"20040027059".pn. and (resistive heat\$3 dielectric permittivity)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 16:57
S38	2	"20040027059".pn. and (electroluminescent material)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 17:12
S39	1	"20040027059".pn. and (wide gap)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 17:21
S40	1	"20040027059".pn. and (polymer vinyl transport)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 17:39
S41	. 1	"20040027059".pn. and (wet polymer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 17:53
S42	1	"20040027059".pn. and (drying temperature glass)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 17:47

S43	92900	glass near2 transition near2 temperature	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 17:48
S44	89530	glass adj transition adj temperature	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 17:48
S45	3719	S44 with organic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 17:48
S46	4327	S44 with substrate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 17:48
S47	33	S18 and S46	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 17:48
S48	0	"20040027059".pn. and (printer printing print\$head exposure)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2006/04/21 18:02
S49	2	"6472817".pn. and layer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 17:57
S50	0	"20030189401".pn. and (printer printing print\$head exposure)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 18:02

S51	1	"20030189401".pn. and (potential difference ev)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 18:03
S52	1	"20030189401".pn. and (electron affinity)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/21 18:04